

ST3DV520E

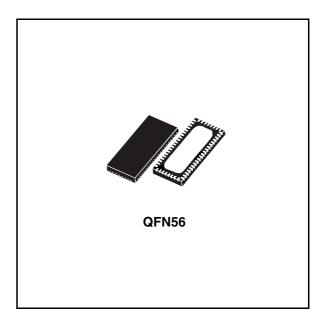
MUX/DEMUX for 4 differential channel LVDS and DDC

Features

- Low R_{ON}: 4.0 Ω typical
- V_{CC} operating range: 3.0 to 3.6 V
- Enhanced ESD protection: > 8 kV (contact) and 15 kV (HBM)
- Channel on capacitance: 9.5 pF typical
- Switching time speed: 9 ns
- Near to zero propagation delay: 250 ps
- Very low crosstalk: -45 dB at 250 MHz
- Bit-to-bit skew: 200 ps
- > 600 MHz -3 dB typical bandwidth (or data frequency)
- Support up to 4 differential LVDS channel
- Support 2 channel for DDC
- Independent SEL control for LVDS and DDC channels
- Package: QFN56

Applications

- Audio/video switching
- High bandwidth physical layer signals routing



Description

The ST3DV520E is a 4 differential channel LVDS multiplexer/demultiplexer low R_{ON} bidirectional switch used to switch between multiple LVDS sources. It is designed for very low crosstalk, low bit-to-bit skew and low I/O capacitance, to maintain high signal integrity.

The differential signal from the LVDS transceiver is multiplexed into one of two selected outputs while the unselected switch goes to Hi-Z status.

The device integrates 2 SPDT (single pole dual throw) switches, for DDC channel.

SEL for LVDS and DDC channel is controlled independently.

Table 1. Device summary

Order code	Package	Packing
ST3DV520EQTR	QFN56	Tape and reel

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1 Pin description

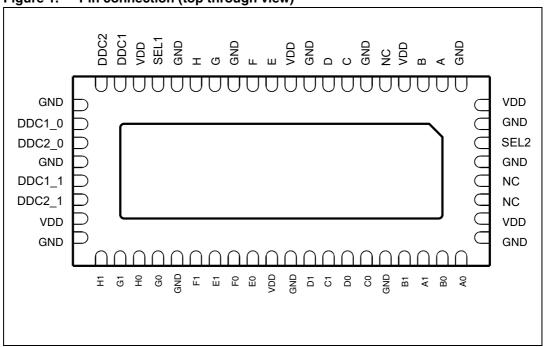


Figure 1. Pin connection (top through view)

Table 2. Pin description

Pin	Symbol	Name and function
2, 3, 7, 8, 11, 12, 14, 15	A, B, C, D, E, F, G, H	8-bit bus
48, 47, 43, 42, 37, 36, 32, 31	A0, B0, C0, D0, E0, F0, G0, H0	8-bit multiplexed to bus 0
46, 45, 41, 40, 35, 34, 30, 29	A1, B1, C1, D1, E1, F1, G1, H1	8-bit multiplexed to bus 1
17	SEL1	LVDS channel selection
54	SEL2	DDC channel selection
19, 20	DDC1, DDC2	DDC switch input
22, 23, 25, 26	DDC1_0, DDC2_0, DDC1_1, DDC2_1	DDC switch output
4, 10, 18, 27, 38, 50, 56	V _{DD}	Supply voltage
1, 6, 9, 13, 16, 21, 24, 28, 33, 39, 44, 49, 53, 55	GND	Ground
5, 51, 52	NC	No internal connection



i igure z.	input equivalent circu	
	A B	
	С	
	D	
	E	E0
	F	F0 E1
		F1
	G H	G0 H0
		G1
		H1
	SEL	
		DDC1_0
	DDC1 —	DDC1_1
	DDC2 —	DDC2_0
	SEL2 _	DDC2_1
		AM08682V1

Figure 2. Input equivalent circuit

Table 3.LVDS switch function table

SEL1	Function
L	8-bit bus to 8-bit multiplexed bus 0
Н	8-bit bus to 8-bit multiplexed bus 1

Table 4.DDC switch function table

SEL2 Function	
L DDC switch input connected to DDC switch output X_0	
Н	DDC switch input connected to DDC switch output X_1



2 Maximum rating

Stressing the device above the rating listed in the "absolute maximum ratings" table may cause permanent damage to the device. These are stress ratings only and operation of the device at these or any other conditions above those indicated in the operating sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

Parameter	Value	Unit
Supply voltage to ground	-0.5 to 4.6	V
DC input output voltage	-0.5 to 4.6	V
DC control input voltage	-0.5 to 4.6	V
DC output current ⁽¹⁾	120	mA
Power dissipation	0.5	W
Storage temperature	-65 to 150	°C
Lead temperature (10 sec)	300	°C
	Supply voltage to ground DC input output voltage DC control input voltage DC output current ⁽¹⁾ Power dissipation Storage temperature	Supply voltage to ground-0.5 to 4.6DC input output voltage-0.5 to 4.6DC control input voltage-0.5 to 4.6DC output current ⁽¹⁾ 120Power dissipation0.5Storage temperature-65 to 150

Table 5. Absolute maximum ratings

1. If $V_{IO} \ge I_O$ does not exceed the maximum limit of P_D .

2.1 Recommended operating conditions

Symbol	Parameter		Unit		
Symbol	Falameter	Min	Тур	Max	Unit
V _{CC}	Supply voltage to ground	3	-	3.6	V
V _{IC} DC control input voltage (SEL1, 2)		0	-	V _{CC}	V
V _{IO}	DC input/output voltage	0	-	V _{CC}	V
Τ _Α	Operating temperature	-40	-	85	°C

Table 6. Recommended operating conditions



3 Electrical characteristics

	Parameter	Test condition	Value -40 to 85 °C			Unit
Symbol						
			Min	Тур	Max	
V _{IH}	Voltage input high (SEL1, 2)	High level guaranteed	2.4	-	-	V
V _{IL}	Voltage input low (SEL1, 2)	Low level guaranteed	-0.5	-	0.8	V
V _{IK}	Clamp diode voltage (SEL1, 2)	V _{CC} = 3.6 V I _{IN} = -18 mA	-	-0.8	-1.2	V
IIH	Input high current (SEL1, 2)	$V_{CC} = 3.6 V$ $V_{IN} = V_{CC}$	-	-	±5	μA
۱ _{۱L}	Input low current (SEL1, 2)	V _{CC} = 3.6 V V _{IN} = GND	-	-	±5	μA
IOFF _(SW) ⁽¹⁾	Leakage current through the switch common terminals (A to H) (DDC1 to DDC2)	$V_{CC} = 3.6 V$ A to H = V _{CC} DDC1 to DDC2 = V _{CC} A0 to H0 = 0 V A1 to H1 = floating DDCx_0 = 0 V DDCx1 = floating SEL1 = V _{CC} , SEL2 = V _{CC}	-	-	±1	μΑ
IOFF _(SEL1)	SEL1 pin leakage current	V _{CC} = 0 V SEL1, 2 = 0 to 3.6 V	-	-	±1	μA
R _{ON}	Switch ON resistance ⁽²⁾	$V_{CC} = 3.0 V$ $V_{IN} = 1.5 \text{ to } V_{CC}$ $I_{IN} = -40 \text{ mA}$	-	4.0	6.5	Ω
R _{FLAT}	ON resistance flatness ⁽²⁾	$V_{CC} = 3.0 V$ V_{IN} at 1.5 and VCC $I_{IN} = -40 mA$	-	0.5	-	Ω
ΔR_{ON}	ON resistance match between channel $\Delta R_{ON} = R_{ONMAX} - R_{ONMIN}$ (2)(4)	$V_{CC} = 3.0 V$ $V_{IN} = 1.5 \text{ to } V_{CC}$ $I_{IN} = -40 \text{ mA}$	-	0.4	1	Ω

Table 7. DC electrical characteristics

1. Refer to Figure 4: Test circuit for leakage current (IOFF) on page 9

2. Measured by voltage drop between channels at indicated current through the switch. ON resistance is determined by the lower of the voltages.

3. Flatness is defined as the difference between the R_{ONMAX} and R_{ONMIN} of ON resistance over the specified range.

4. ΔR_{ON} measured at same V_{CC}, temperature and voltage level.



	Table 6. Capacitance $(T_A = 25 \text{ C}, T = 1 \text{ Min}2)$					
Symbol	Parameter	Test condition	Value			Unit
Symbol			Min	Тур	Max	Onit
C _{IN}	SEL1, 2 pin input capacitance ⁽¹⁾	DC = 0.25 V AC = 0.5 V _{PP} f = 1 MHz	-	2	3	pF
C _{OFF}	Switch off capacitance ⁽²⁾	DC = 0.25 V AC = 0.5 V _{PP} f = 1 MHz	-	4	5	pF
C _{ON}	Switch on capacitance ⁽³⁾	DC = 0.25 V AC = 0.5 V _{PP} f = 1 MHz	-	9.5	11	pF

Table 8. Capacitance ($T_A = 25 \degree C$, f = 1 MHz)

1. Refer to *Figure 5 on page 10*

2. Refer to Figure 6 on page 10

3. Refer to *Figure 7 on page 11*

Table 9.Power supply characteristics

	Parameter	Test condition	Value -40 to 85 °C			Unit
Symbol						
			Min	Тур	Max	
Icc	Active mode power supply current	V_{CC} = 3.6 V, V_{IN} = V_{CC} or GND	-	150	500	μA

Table 10.	Dynamic electrical characteristics (V _{CC} = 3.3 V ±10%)
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Symbol	Parameter	Test condition	Value -40 to 85 °C			Unit
			Min	Тур	Мах	
X _{talk}	Crosstalk ⁽¹⁾	R _L = 100 Ω f = 250 MHz	-	-45	-	dB
O _{IRR}	Off isolation ⁽²⁾	R _L = 100 Ω f = 250 MHz	-	-37	-	dB
BW	-3 dB bandwidth ⁽³⁾	R _L = 100 Ω 0 < V _{IN} ≤3.6 V	-	600	-	MHz

1. Refer to *Figure 9 on page 12*

2. Refer to *Figure 10 on page 13*

3. Refer to *Figure 8 on page 11*



Symbol	Parameter	Test condition	Value			11
			Min	Тур	Max	Unit
t _{PD}	Propagation delay	V _{CC} = 3 to 3.6 V	-	0.25	-	ns
t _{PZH} , t _{PZL}	Line enable time, SEL to x to x0 or x to x1	V _{CC} = 3 to 3.6 V	0.5	6.5	15	ns
t _{PHZ} , t _{PLZ}	Line disable time, SEL to x to x0 or x to x1	V _{CC} = 3 to 3.6 V	0.5	6.5	8.5	ns
t _{SK(O)}	Output skew between center port to any other port	V _{CC} = 3 to 3.6 V	-	0.1	0.2	ns
t _{SK(P)}	Skew between opposite transition of the same output (t _{PHL} , t _{PLH})	V _{CC} = 3 to 3.6 V	-	0.1	0.2	ns

Table 11. Switching characteristics ($T_A = 25 \text{ °C}$, $V_{CC} = 3.3 \text{ V} \pm 10\%$)

Table 12.ESD performance

Symbol	Test condition	Value			Unit
Symbol	Test condition	Min	Тур	Мах	Onnt
ESD	Contact discharge ⁽¹⁾ IEC61000-4-2	-	±8	-	kV
	Human body model (MIL-STD-883)	-	±15	-	kV

1. Refer to Figure 3: Diagram for suggested VDD decoupling on page 9.



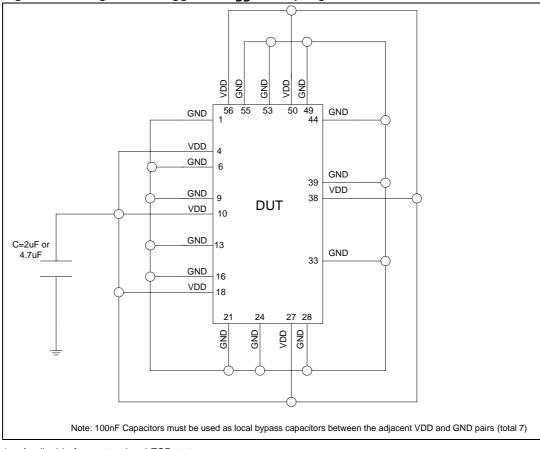


Figure 3. Diagram for suggested V_{DD} decoupling

1. Applicable for system level ESD test

Figure 4. Test circuit for leakage current (I_{OFF})

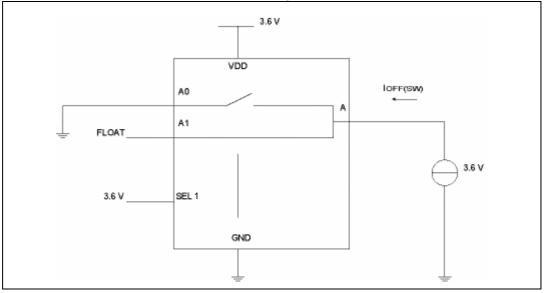
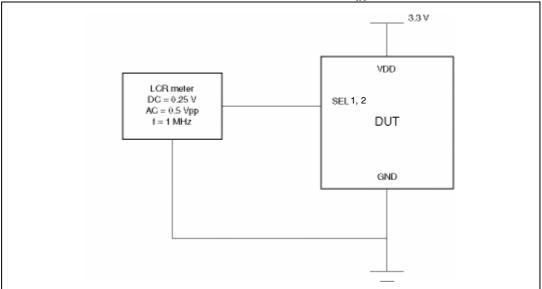
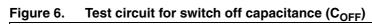
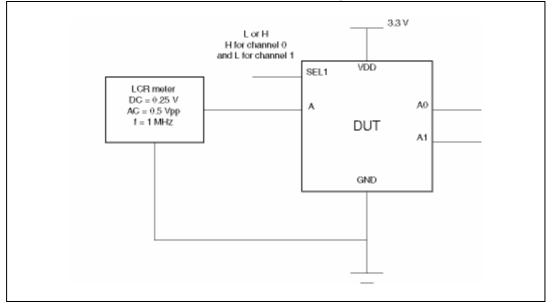




Figure 5. Test circuit for SEL pin input capacitance (C_{IN})









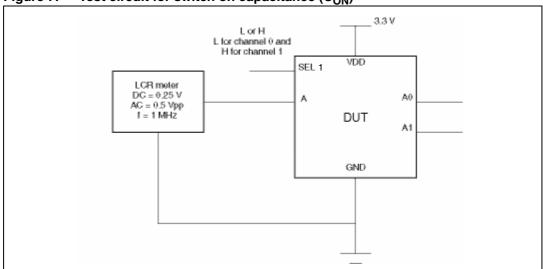
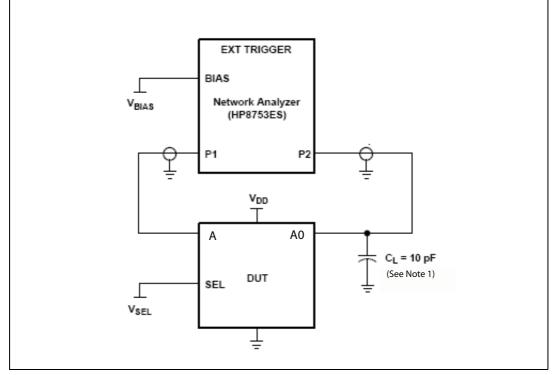


Figure 7. Test circuit for switch on capacitance (C_{ON})





1. C_L includes proble and jig capacitance.



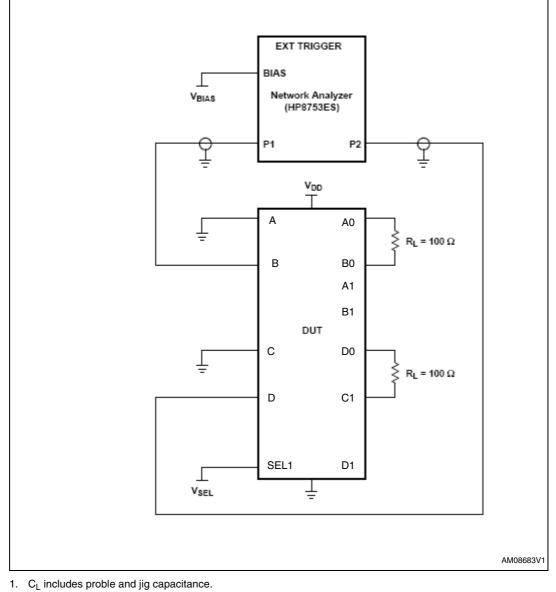
Frequency response is measured at the output of the ON channel. For example, when $V_{SEL1} = 0$ and A is the input, the output is measured at A0. All unused analog I/O ports are left open.

HP8753ES setup:

Average = 4 R_{BW} = 3 kHz V_{BIAS} = 0.35 V ST = 2 s

P1 = 0 dBm

Figure 9. Test circuit for crosstalk measurement (x_{talk})



2. A 50 Ω termination resistor is needed to match the loading of the network analyzer.



Crosstalk is measured at the output of the non-adjacent ON channel. For example, when $V_{SEL1} = 0$, and B is the input, the output is measured at D. All unused analog input ports are connected to GND and output ports are left open.

HP8753ES setup: Average = 4 R_{BW} = 3 kHz V_{BIAS} = 0.35 V ST = 2 s P1 = 0 dBm

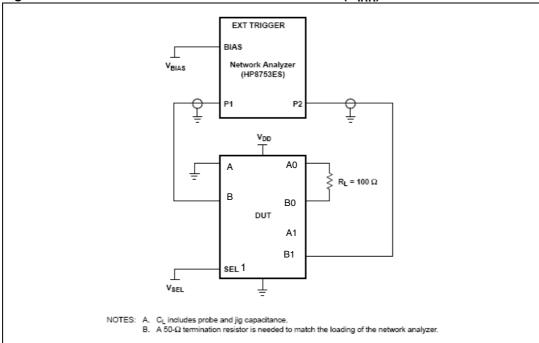


Figure 10. Test circuit for off isolation measurement (O_{IRR})

Off isolation is measured at the output of the OFF channel. For example, when V_{SEL1}=0, and B is the input, the output is measured at B1. All unused analog input ports are connected to GND and output ports are left open.

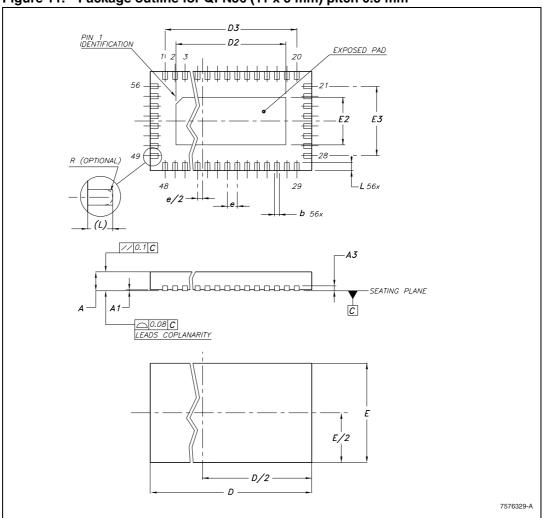
HP8753ES setup:

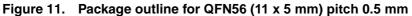
Average = 4 R_{BW} = 3 kHz V_{BIAS} = 0.35 V ST = 2 s P1 = 0 dBm



4 Package mechanical data

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK[®] packages, depending on their level of environmental compliance. ECOPACK[®] specifications, grade definitions and product status are available at: www.st.com. ECOPACK[®] is an ST trademark.







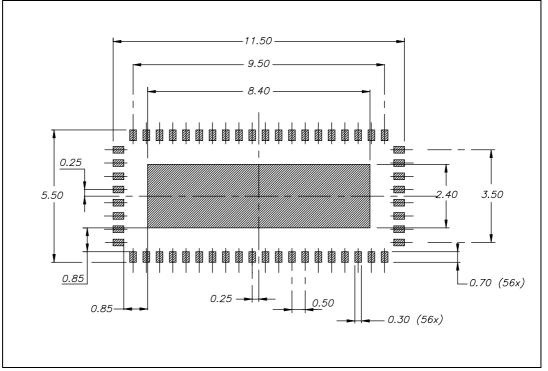
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Cumple of	Millimeters			
Symbol	Min	Тур	Мах	
А	0.70	0.75	0.80	
A1	-	-	0.05	
A3	-	0.20	-	
b	0.20	0.25	0.30	
D	10.90	11.00	11.10	
D2	8.30	8.40	8.50	
D3	-	9.50	-	
E	4.90	5.00	5.10	
E2	2.30	2.40	2.50	
E3	_	3.50	_	
е	_	0.50	_	
L	0.30	0.40	0.50	

Table 13. Mechanical data for QFN56 (11 x 5 mm) pitch 0.5 mm







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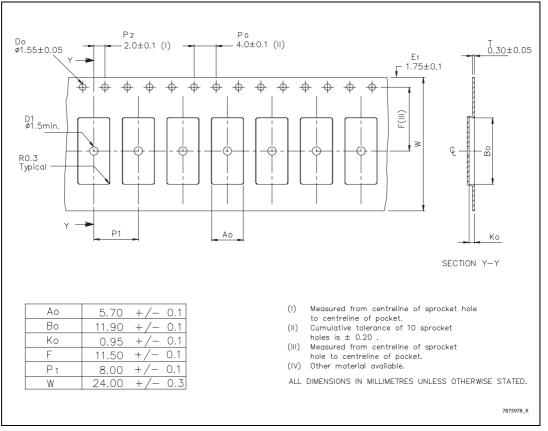


Figure 13. Carrier tape information for QFN56 (11 x 5 mm) pitch 0.5 mm



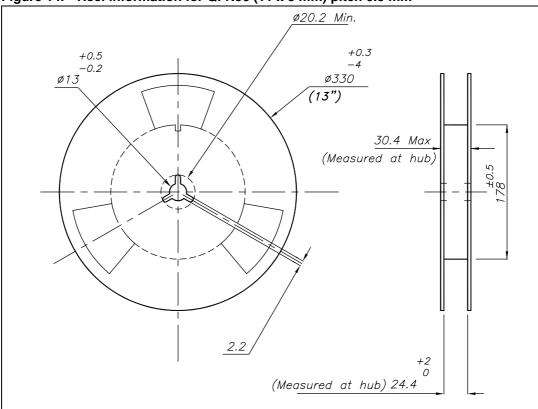


Figure 14. Reel information for QFN56 (11 x 5 mm) pitch 0.5 mm



5 Revision history

Table 14. Document revision history

Date	Revision	Changes
08-Dec-2010	1	Initial release.



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